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FDS6875 Dual P-Channel 2.5V Specified PowerTrench[™] MOSFET

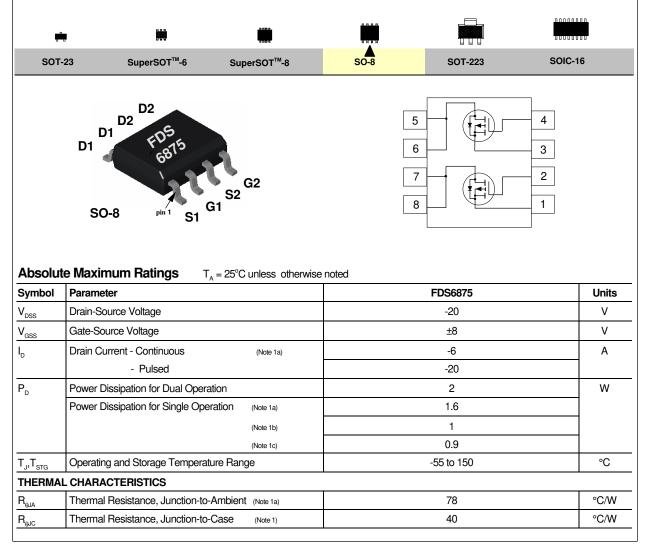
General Description

These P-Channel 2.5V specified MOSFETs are produced using ON Semiconductor's advanced PowerTrench process that has been especially tailored to minimize the on-state resistance and yet maintain low gate charge for superior switching performance.

These devices are well suited for portable electronics applications: load switching and power management, battery charging and protection circuits.

Features

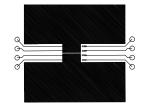
- $\label{eq:generalized_states} \begin{array}{c} \bullet & \mbox{-6 A, -20 V. } R_{\rm DS(ON)} = 0.030 \; \Omega \; @ V_{\rm GS} = -4.5 \; V, \\ R_{\rm DS(ON)} = 0.040 \; \Omega \; @ V_{\rm GS} = -2.5 \; V. \end{array}$
- Low gate charge (23nC typical).
- High performance trench technology for extremely low R_{DS(ON)}.
- High power and current handling capability.



Symbol	Parameter	Conditions	Min	Тур	Max	Units
OFF CHAR	ACTERISTICS			•		
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_{D} = -250 \mu A$	-20			V
$\Delta BV_{DSS} / \Delta T_{J}$	Breakdown Voltage Temp. Coefficient	I_{D} = -250 μ A, Referenced to 25 °C		-21		mV/ºC
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -16 V, V_{GS} = 0 V$			-1	μA
		$T_{J} = 55^{\circ}C$			-10	μA
I _{GSSF}	Gate - Body Leakage, Forward	$V_{GS} = 8 V, V_{DS} = 0 V$			100	nA
	Gate - Body Leakage, Reverse	$V_{gs} = -8 V, V_{Ds} = 0 V$			-100	nA
	CTERISTICS (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{\rm DS} = V_{\rm GS}, \ I_{\rm D} = -250 \ \mu A$	-0.4	-0.8	-1.5	V
$\Delta V_{GS(th)} / \Delta T_J$	Gate Threshold Voltage Temp. Coefficient	$I_{\rm D}$ = 250 μ A, Referenced to 25 °C		2.8		mV/°C
R _{DS(ON)}	Static Drain-Source On-Resistance	$V_{GS} = -4.5 \text{ V}, \ I_{D} = -6 \text{ A}$		0.024	0.03	Ω
		T _J =125°C		0.033	0.048	
		$V_{GS} = -2.5 \text{ V}, I_{D} = -5.3 \text{ A}$		0.032	0.04	
I _{D(ON)}	On-State Drain Current	$V_{GS} = -4.5 \text{ V}, V_{DS} = -5 \text{ V}$	-20			Α
9 _{FS}	Forward Transconductance	$V_{DS} = -4.5 \text{ V}, \ I_{D} = -6 \text{ A}$		22		S
DYNAMIC (CHARACTERISTICS	·	•		•	
C _{iss}	Input Capacitance	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1.0 MHz		2250		pF
C _{oss}	Output Capacitance			500		pF
C _{rss}	Reverse Transfer Capacitance			200		pF
SWITCHING	CHARACTERISTICS (Note 2)		_	-		
t _{D(on)}	Turn - On Delay Time	$V_{\rm DS}$ = -10 V, I _D = -1 A		8	16	ns
ţ,	Turn - On Rise Time	$V_{_{GEN}} = -4.5 \text{ V}, \text{ R}_{_{GEN}} = 6 \ \Omega$		15	27	ns
t _{D(off)}	Turn - Off Delay Time			98	135	ns
t _r	Turn - Off Fall Time			35	55	ns
Q	Total Gate Charge	$V_{\rm DS} = -10 \ V, \ I_{\rm D} = -6 \ A,$		23	31	nC
Q _{gs}	Gate-Source Charge	$V_{GS} = -5 V$		3.9		nC
Q _{gd}	Gate-Drain Charge			5.5		nC
DRAIN-SOU	IRCE DIODE CHARACTERISTICS AND MAX	(IMUM RATINGS		-		
l _s	Maximum Continuous Drain-Source Diode Forward Current				-1.3	А
V _{SD}	Drain-Source Diode Forward Voltage	$V_{\rm GS} = 0 \ V, \ I_{\rm S} = -1.3 \ A \ (Note 2)$		-0.7	-1.2	V

Notes:

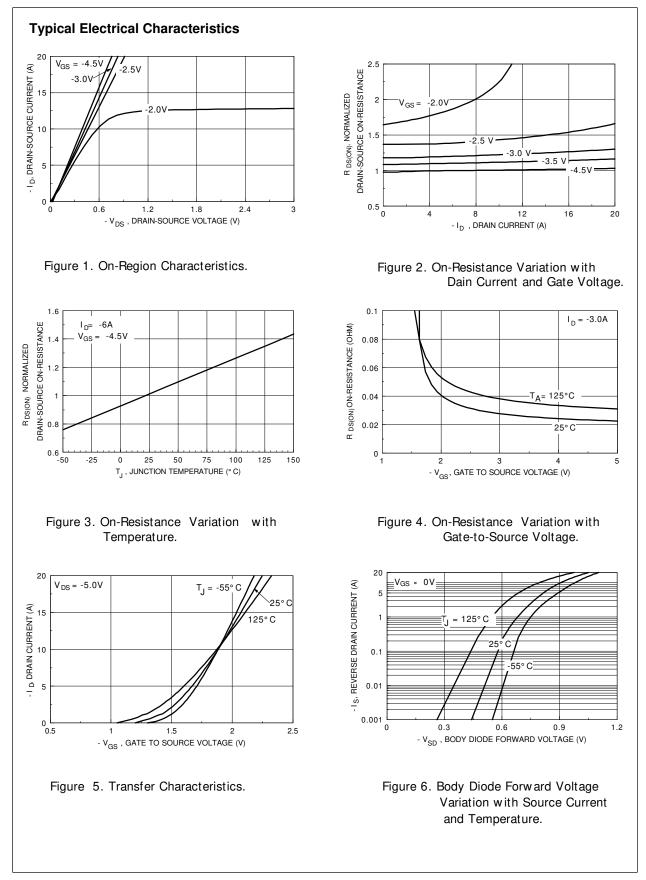
1. R_{BM} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{BM} is guaranteed by design while R_{BM} is determined by the user's board design.



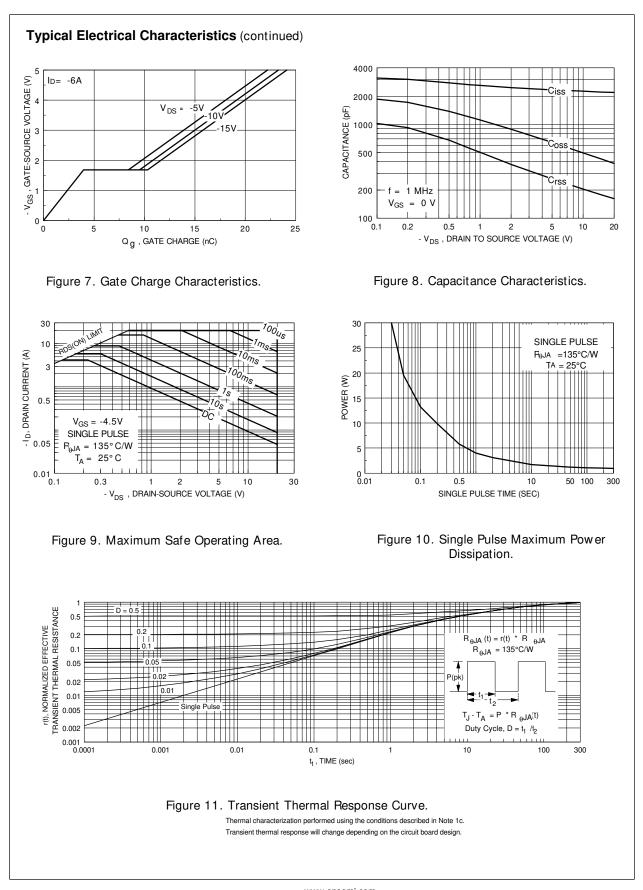
a. 78°C/W on a 0.5 in² pad of 2oz copper. b. 125°C/W on a 0.02 in² pad of 2oz copper. c. 135°C/W on a 0.003 in² pad of 2oz copper.

Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width <_ 300 μ s, Duty Cycle <_ 2.0%.



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